Page 1 (No. of pages 4)
MINISTRY OF AVIATION DLRD/RRE

Specification: MOA/CV2391/2	SECURITY			
Issue 3 Dated July 1962	<u>Specification</u>	Valve		
To be read in conjunction with K1007	Unclassified	Unclassified		

Indicates a change

TYPE OF VALVE: Silicon mixer crystal diode PROTOTYPE: CV2391 - VX3136 CV2392 - VX3171				MARKING C.V. Number and if possible, the Factory Code and Date Code - see K1007/4				
RATINGS and CHARACTERIS (Not for Inspection Purp	DIMENSIONS As K1007/A1/ See Note 8, page 4							
All limiting values are	absolut	e :	Note	POLARITY				
Max. Operating temperature	(°c)	100		CV2391: Red mark on body				
Max. storage temperature	(°c)			indicates positive polarity of pin.				
Min. storage temperature	(°c)	- 55						
Max. burnout (a) r.f. spikes (b) d.c. spikes	(ergs) (ergs)	0.1 0.04	A	CV2392: Green mark on body indicates negative polarity of pin.				
Max. load resistance	(ohms)	20	В	See K1007/4				
Max. forward resistance (at 0.5 V)	(ohms)	750	С	See K1007/4				
Min. reverse resistance (at -0.5 V) (kohms)	10	С	PACKAGING				
	kMc/s) kMc/s)	26 40		See K1005				
Max. noise factor	(đB)	16.5	D	In K1005/8.1 read "metal				
Typical operating rectified current	(mA)	0.5	E	foil" instead of "lead foil"				

NOTES

- A. For min. of 90% survival, due to magnetron spikes. The user is warned that the crystal can also be damaged by excessive voltage of an oscillatory or transient nature.
- B. This includes resistance of meter and that of any filter network in series with diode.
- C. It is recommended that the crystal diode is replaced in service when the d.c. characteristics fall outside either of these values.
- D. For i.f. amplifier noise factor of 2 dB.
- E. Rectified current for optimum performance depends on noise factor of i.f. amplifier and amount of local oscillator noise. With negligible local oscillator noise and i.f. noise factor of about 2 dB, the rectified current should be between 0.3 and 1.0 mA.

TEMPERATURE: 15-30°C

SOURCE IMPEDANCE: V.S.W.R. 1.05 max. at signal and image frequencies

LOAD RESISTANCE: 15 ohms max.

TEST HOLDERS: Note 1 STANDARDS: Note 2

K1007	Test	Test Conditions	AOL	Insp. Level	Sym.	Limits		Units	
				18	Level		Min.	Max.	
_	Group A - omitted	ļ 							
	GROUP B								
	Reverse current	¥ _r = -0.5	• v	0.65	11	Ir	-	25	ΛυA
5A. 4	Noise factor	34,860 ±		0.65	11	N	_	12.5	đВ
		I _o = 0.5 i.f. ampl factor =	ifier noise						
		Note 3			.				
	GROUP C								
5 A. 3	Rectifier Admittance(1)		ower = 1,000	2.5	I	VSW R	-	1.8	Ratio
	or		.5 ± .05 mA						
5A. 5	i.f. impedance	(a) L.O. ± 15%	power = 1,000	2.5	I	R _{if}	300	600	ohms
	or	_	•5 <u>+</u> •05 mA quency = 45 <u>+</u>						
	Forward current	Note 4 V _f = 0.5	v	2.5	I	I _f	1.5		mA.
	GROUP D								
	Resistance to voltage breakdown (burnout)	r.f. leve Note 5	l = 0.15 ergs	No	te 6	n ^d n	-	16.5 2.0	
	GROUP E	Combined	AQL	10				!	
10.2	TEMPERATURE CYCLING	3 cycles: +100°C Note 7	-55°C to		16	:			
	Post temperature cycling test	•							
8	Inoperatives Reverse current	As in Gro	oup B	6.5 6.5		ı,	-	40	/UA
	Noise factor	As in Gro Note 5	_	6.5		N An	_	16.5 2	dub dub

CT2391-2/3/2

K1007	Test	Test Conditions	AQL %	Insp. Level	Sym.	Limits		
						Min.	Max.	Unit
11.1	AXIAL TENSION	Force of 10 lbs.	6.5	IC				
11.3	FATIGUE	No voltages		QA				
11.4	SHOCK	Hammer angle = 20°		QA				
	Post fatigue and shook tests							
8	Inoperatives							
	Reverse current	As in Group B			I _r	-	40	Αע
	Noise factor	As in Group B			N	-	16.5	dB
		Note 5			ΔN	<u> </u>	2	dB
•••	GROUP F							
13	LIFE	To be agreed		IA				
13.3	Post life tests							ļ
8	Inoperatives		6.5					
	Reverse current	As in Group B	6.5		Ir	-	40	μA
	Noise factor	As in Group B	6.5		N	-	16.5	
		Note 5			$\Delta_{\mathbf{N}}$	-	2	dB
13.4	STORAGE LIFE(1)	No voltages. Note 7 Tamb = -55°C t = 150 h			1			
13.5	STORAGE LIFE(2)	No voltages T _{amb} = +100°C t = 150h			I			
	Post storage tests	Combined AQL for	ļ					
	Repeat Group B tests to Group F limits	(a) Storage Life (1) (b) Storage Life (2)	4.0					
	GROUP G	· · · · · · · · · · · · · · · · · · ·						
5.3.2	.11 Retest after 28 days holding period							
8	Inoperatives		0.5%	100%				
	Noise factor	As in Group B	2.0%	100%	N	-	16.5	dE

NOTES

- 1. All test and standard holders shall conform to RRE Drawing BRR/222727. Test holders should give the same VSWR as the appropriate standard holder within ± 2%.
- 2. Crystals shall not be used as standards for measurement of any parameter, but may be used as transfer standards. The standard admittance shall be defined by holders supplied by the Approving Authority. Calibrated crystals will also be supplied for the noise factor test (Note 3).
- 3. The standard of reference shall be a noise tube type VX9166, assuming a noise level of 16.0dB above thermal for a discharge current of 100 mA. Any approved method of measurement may be used with allowance for experimental error.
- 4. The standard of reference shall be a RC7K resistor within the range 430-510 ohms, mounted axially in a holder having the same socket dimensions as a CV2391, with lead lengths less than 0.125 inch. The resistance shall be assumed equal to the d.c. value.
- 5. The limit applied shall be that which is more favourable to the crystal, i.e. a crystal that changes from say 14.0 dB to 16.4 dB is acceptable as is one that changes from say 15.3 dB to 17.3 dB.
- 6. The crystal diodes for subjecting to this test shall be obtained by either of the following methods:-
 - (a) 100 completed diodes selected at random from the diodes made from each ingot of semiconductor material which are satisfactory after Group B tests.
 - or (b) random slices from each ingot of semiconductor material are subjected to all normal processing and sufficient semiconductor elements, (wafers) are selected at random and assembled to provide 100 completed diodes satisfactory after Group B tests.

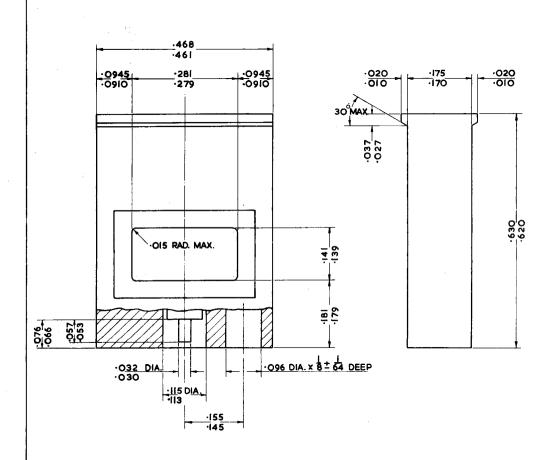
The burnout test of 5,000 pulses may be at a level of 0.15 erg r.f. or 0.06 erg d.c. (K1007/5A.2) at the discretion of the diode manufacturer.

If more than 50 diodes (of the 100 above) fail this test the ingot and all diodes subjected to the test shall be rejected.

Crystal diodes from an acceptable ingot which pass this test and are also satisfactory on Group B tests will be accepted for delivery but not for tests subsequent to Group B.

- 7. These crystal diodes are not hermetically sealed; precautions must therefore be taken to prevent the formation of frost during low temperature tests.
- 8. The dimensions are as in Issue 2 but with minor amendments.

THIRD ANGLE PROJECTION DIMENSIONS IN INCHES



FINISH: BODY- NICKEL PLATE PIN - SILVER PLATE